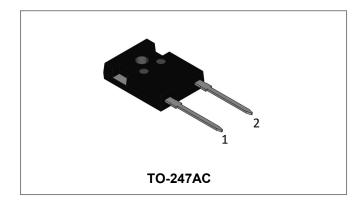


Technical Data Data Sheet N2850, Draft





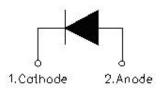
### SDUR30F120W ULTRAFAST RECTIFIER



#### **Applications:**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

### **Circuit Diagram**



#### Features:

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: 100% Pure Tin
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# Maximum Ratings@TA=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	1200	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=98°C, In DC	30	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	200	Α

- China Germany Korea Singapore United States
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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 30A, Pulse, T <sub>J</sub> = 25°C	-	3.20	V
	V <sub>F2</sub>	@ 30A, Pulse, T <sub>J</sub> = 125°C	-	3.00	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> ,T <sub>J</sub> =25°C	-	10	uA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> =125°C	-	4	mA
Reverse Recovery Time	t <sub>rr</sub>	$I_F$ =500mA, $I_R$ =1A,and $I_m$ =250mA, $T_J$ =25°C	-	60	ns

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> JC	DC operation	0.80	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

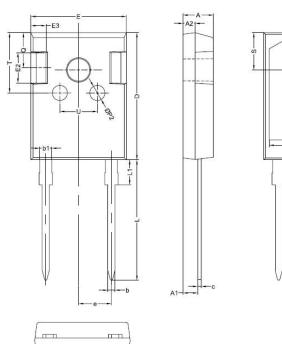


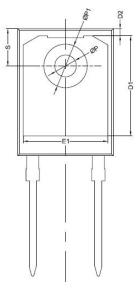
**Technical Data** Data Sheet N2850, Draft





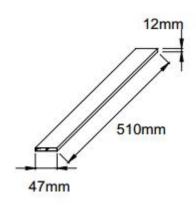
## **Mechanical Dimensions TO-247AC**



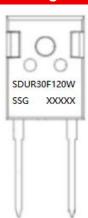


CVMDOL	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
Α	4.80	5.00	5.20		
A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.35		
b1	1.80	2.00	2.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.58			
D2		1.17			
E	15.60	15.80	16.00		
E1		14.02			
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.42		
L1		4.13			
Р	3.50	3.60	3.70		
P1	7.1	7.19	7.40		
P2		2.50			
Q		5.80			
S	6.05	6.15	6.25		
Т		10.00			
U		6.20			

### **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

SDUR

= Device Type = Forward Current (30A) 30

= Reverse Voltage (1200V) 120

W = Configuration SSG = SSG

= Year WW = Week = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

## **Ordering Information:**

Device	Package	Shipping
SDUR30F120W	TO-247AC(Pb-Free)	25pcs / tube

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •

#### SDUR30F120W



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